# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





#### **General Description**

The MAX44259/MAX44260/MAX44261/MAX44263 offer a unique combination of high speed, precision, low noise, and low-voltage operation making them ideally suited for a large number of signal processing functions such as filtering and amplification of signals in portable and industrial equipment.

The devices' rail-to-rail input/outputs and low noise guarantee maximum dynamic range in demanding applications such as 12- to 14-bit SAR ADC drivers. Unlike traditional rail-to-rail input structures, input crossover distortion is absent due to an optimized input stage with an ultra-quiet charge pump.

The MAX44260 includes a fast-power-on shutdown mode for further power savings. The MAX44261 offers a unique on-demand calibration pin where the user can invoke self-trimming of the input offset voltage. The MAX44263 is a dual amplifier.

The family of parts operates from a supply range of 1.8V to 5.5V over the -40°C to +125°C temperature range and can operate down to 1.7V over the 0°C to +70°C temperature range. The MAX44259 is offered in a 5-pin SOT23 package. The MAX44260/MAX44261 are available in small, 6-pin SC70 packages. The MAX44260 is also available in a 1mm x 1.5mm thin  $\mu$ DFN (ultra-thin LGA) package. The MAX44263 is available in a small 8-pin SC70 package.

Visit <u>www.maximintegrated.com/products/patents</u> for product patent marking information.

Ordering Information appears at end of data sheet.

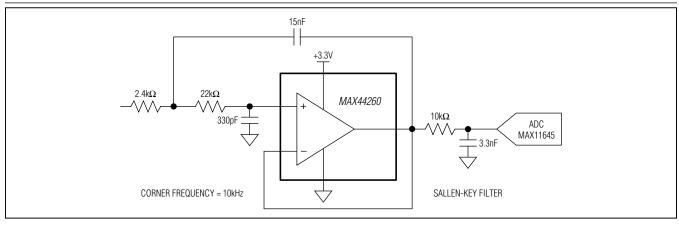
#### **Benefits and Features**

- Low Noise for Higher System Accuracy
  - 12.7nV/VHz Input Voltage-Noise Density
  - 1.2fA/\/Hz Input Current-Noise Density
  - 50µV (max) Vos at +25°C
  - 110dB Total Harmonic Distortion
- 15MHz Unity-Gain Bandwidth Enables for High-Bandwidth Applications
- Low Power Extends the Battery Life of Portable Equipment
  - 500fA Low Input Bias Current
  - 750µA Quiescent Current per Amplifier
  - < 1µA Supply Current in Shutdown</li>
- On-Demand V<sub>OS</sub> Self-Calibration (MAX44261)
- ♦ Saves Board Space
  - Small, 2mm x 2mm SC70 and 1mm x 1.5mm Thin  $\mu DFN$  (MAX44260) and SOT23 (MAX44259) Packages
- Wide Supply Range from 1.8V to 5.5V Simplifies Power-Supply Requirements

#### **Applications**

Notebooks 3G/4G Handsets Portable Media Players Portable Medical Instruments Battery-Operated Devices Analog-to-Digital Converter Buffers Transimpedance Amplifiers

### **Typical Application Circuit**



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maximintegrated.com.

#### **ABSOLUTE MAXIMUM RATINGS**

IN+, IN-, OUT(V <sub>SS</sub> - 0	0.3V) to (V <sub>DD</sub> + 0.3V)
V <sub>DD</sub> to V <sub>SS</sub>	0.3V to +6V
SHDN, CAL	0.3V to +6V
Output to Short-Circuit Ground Duration	10s
Continuous Input Current into Any Pin	±20mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$	C)
SC70 (derate 3.1mW/°C above +70°C)	245mW

SOT23 (derate 3.9mW/°C above +70°C)	312.6mW
6-Pin Thin µDFN (Ultra-Thin LGA)	
(derate 2.1mW/°C above +70°C)	110.2mW
Operating Temperature Range	40°C to +125°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### PACKAGE THERMAL CHARACTERISTICS (Note 1)

C	$\sim$	7	h
J	U	1	J

Junction-to-Ambient Thermal Resistance ( $\theta_{JA}$ ).... 326.5°C/W Junction-to-Case Thermal Resistance ( $\theta_{JC}$ )......115°C/W SOT23

 Thin µDFN (Ultra-Thin LGA)

Junction-to-Ambient Thermal Resistance  $(\theta_{JA})$  ...... 470°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{DD} = 3.3V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, RL = 10k\Omega$  to  $V_{DD}/2, V_{\overline{CAL}} = V_{\overline{SHDN}} = V_{DD}, T_A = -40^{\circ}C$  to +125°C. Typical values are at T<sub>A</sub> = +25°C, unless otherwise noted.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	МАХ	UNITS
DC CHARACTERISTICS							
Input Voltage Range	VIN+ VIN-	Guaranteed by CN	Guaranteed by CMRR test			VDD + 0.1	V
		TA = +25°C			10	50	
Input Offect Vielterse (Nets 2)	Maa	$T_A = -40^{\circ}C \text{ to } +123^{\circ}C$	5°C after calibration			100	
Input Offset Voltage (Note 3)	Vos	$T_A = -40^{\circ}C$ to	MAX44260/MAX44261			500	μV
		+125°C	MAX44259/MAX44263			800	
Input Offset Voltage Drift	Voc TC	MAX44260/MAX44	4261		0.8	5	μV/°C
(Note 3)	V <sub>OS</sub> - TC	MAX44259/MAX44	1263		1	8	
	IB	T <sub>A</sub> = +25°C	MAX44259/ MAX44260/MAX44261		0.01	0.5	
			MAX44263		0.01	0.5	
Input Bias Current (Note 3)		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$				10	рА
		T <sub>A</sub> = -40°C to +125°C	MAX44259/ MAX44260/MAX44261			100	
		+125 C	MAX44263			160	
Input Capacitance	CIN				0.4		рF
Common-Mode Rejection Ratio	CMRR	VCM = -0.1V to (VDD + 0.1V)		75	90		dB
Input Resistance	RIN	Common mode	$V_{CM} = -0.1V$ to ( $V_{DD} + 0.1V$ )		1011		Ω
		Differential mode			10 <sup>12</sup>		

#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = 3.3V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 10k\Omega$  to  $V_{DD}/2, V_{\overline{CAL}} = V_{\overline{SHDN}} = V_{DD}, T_A = -40^{\circ}C$  to +125°C. Typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.) (Note 2)

PARAMETER	SYMBOL	co	NDITIONS	MIN	ТҮР	MAX	UNITS
		$0.4V \le V_{OUT}$ $\le V_{DD} - 0.4V$ ,	MAX44259/ MAX44260/MAX44261	100	115		
		$R_{OUT} = 10k\Omega$	MAX44263	97	115		
Open-Loop Gain	AOL	$0.4V \le V_{OUT}$ $\le V_{DD} - 0.4V$ ,	MAX44259/ MAX44260/MAX44261	91	100		dB
		$R_{OUT} = 600\Omega$	MAX44263	86	100		
		$0.4V \le V_{OUT} \le V_{D}$	D - 0.4V, R <sub>OUT</sub> = 32Ω		80		
Output Short-Circuit Current	Isc	To V <sub>DD</sub> or V <sub>SS</sub>			50		mA
		Rout = $10k\Omega$				20	
	Vol - Vss	$R_{OUT} = 600\Omega$				50	
	*33	Rout = $32\Omega$			400	700	
		Rout = $10k\Omega$	MAX44259/ MAX44260/MAX44261			10	
Output Voltage Swing			MAX44263			10	- mV -
	Vdd - Voh	$R_{OUT} = 600\Omega$	MAX44259/ MAX44260/MAX44261			40	
			MAX44263			50	
		$R_{OUT} = 32\Omega$			400	800	
AC CHARACTERISTICS							
Input Voltage-Noise Density	en	f = 10kHz			12.7		nV/√Hz
Input Current-Noise Density	in	f = 10kHz			1.2		fA/√Hz
Gain-Bandwidth Product	GBWP				15		MHz
Slew Rate	SR				7		V/µs
Settling Time		$V_{OUT} = 2V_{P-P}, V_{D}$ $C_{L} = 30pF (load),$	DD = 3.3V, AV = 1V/V, settle to 0.01%		1.7		μs
Capacitive Loading	CLOAD	No sustained osc	illation		300		рF
Total Harmonic Distortion	THD	f = 10kHz, V <sub>O</sub> = 2	$V_{P-P}, A_V = 1, R_{OUT} = 10k\Omega$		-110		dB
Output Transient Recovery Time		$\Delta V_{OUT} = 0.2V, V_{DD} = 3.3V, Av = 1V/V;$ R <sub>S</sub> = 20 $\Omega$ , C <sub>L</sub> = 1nF (load)			1		μs
POWER-SUPPLY CHARACTERI	STICS	•					
	) /= -	Guaranteed by PSRR $T_A = 0^{\circ}C$ to +70°C		1.8		5.5	
Power-Supply Range	Vdd			1.7		5.5	V
Power-Supply Rejection Ratio	pply Rejection Ratio PSRR V	Vcm = Vdd/2	MAX44259/MAX44260/ MAX44261	82	95		dB
· · · ·			MAX44263	76	95		

#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = 3.3V, V_{SS} = 0V, V_{IN+} = V_{IN-} = V_{DD}/2, R_L = 10k\Omega$  to  $V_{DD}/2, V_{\overline{CAL}} = V_{\overline{SHDN}} = V_{DD}, T_A = -40^{\circ}C$  to +125°C. Typical values are at T<sub>A</sub> = +25°C, unless otherwise noted.) (Note 2)

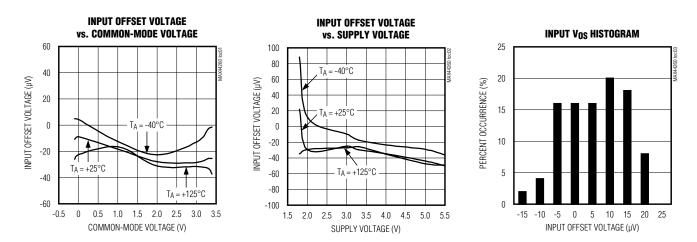
PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
Outer and Outer		MAX44259/MAX44260/MAX44261		750	1200	
Quiescent Current	IDD	MAX44263 (per amplifier)		650	1100	μA
Shutdown Supply Current	ISHDN	(Note 4)			1	μA
Shutdown Input Low	VIL	(Note 4)			0.5	V
Shutdown Input High	VIH	(Note 4)	1.3			V
Output Leakage Current in Shutdown	ISHDN	(Note 4)		100		рА
		MAX44260			1	<u>^</u>
Shutdown Input Bias Current	∣пг∕пн	MAX44261			0.1	μA
Shutdown Turn-On Time	10000	T <sub>A</sub> = +25°C (Note 3)		14.4	18.9	
(Note 4)	<b>t</b> SHDN	T <sub>A</sub> = -40°C to +125°C (Note 3)			26.7	μs
	1011	$T_A = +25^{\circ}C$ (Note 3)		9.7	15.2	
Turn-On Time (Note 4)	ton	T <sub>A</sub> = -40°C to +125°C (Note 3)			18.4	ms

**Note 2:** All devices are 100% production tested at  $T_A = +25$ °C. Temperature limits are guaranteed by design.

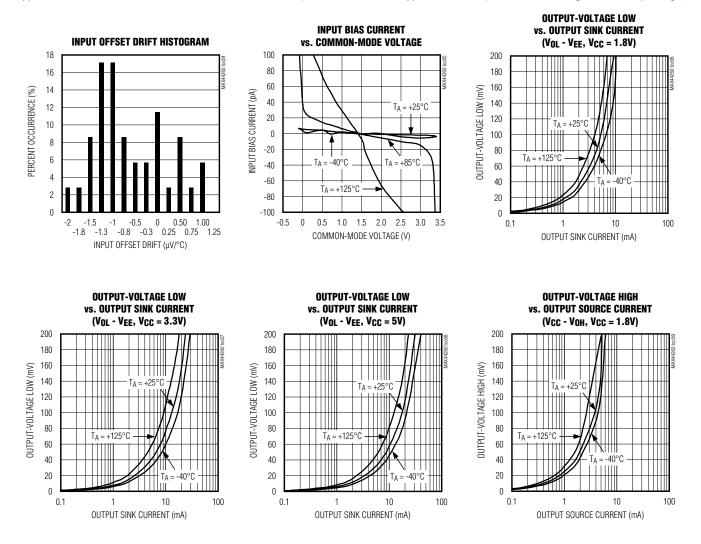
Note 3: Guaranteed by design.

Note 4: MAX44259/MAX44260/MAX44261 only.

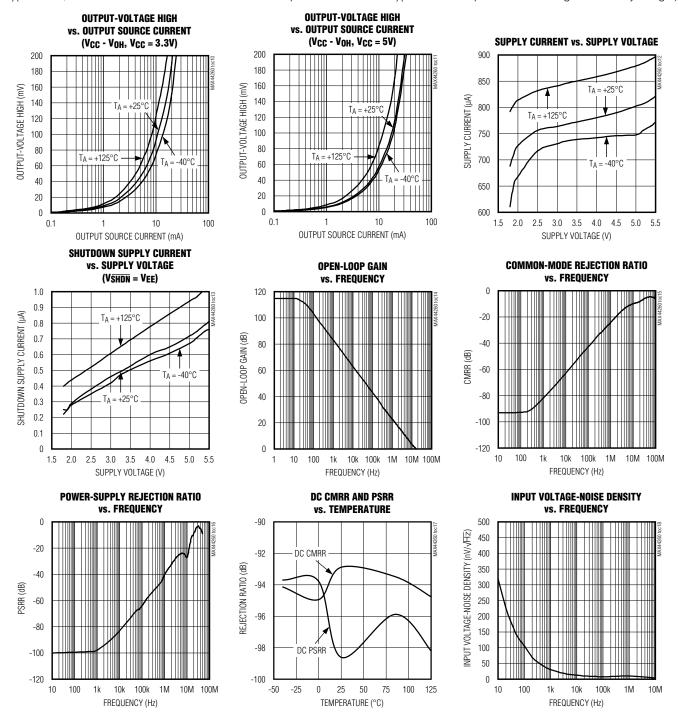
### **Typical Operating Characteristics**



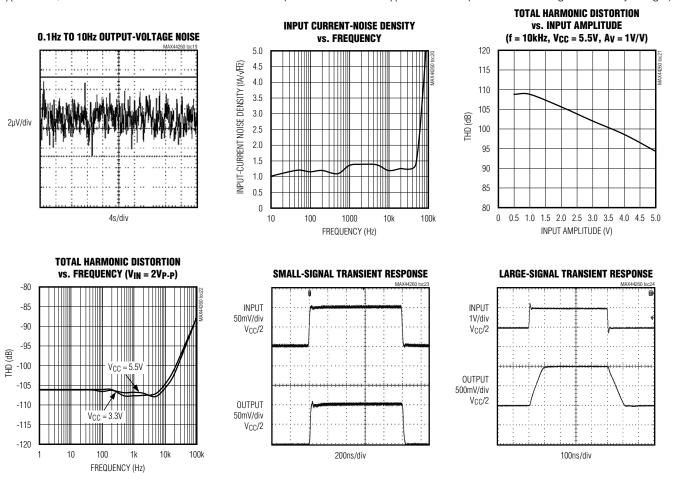
### **Typical Operating Characteristics (continued)**



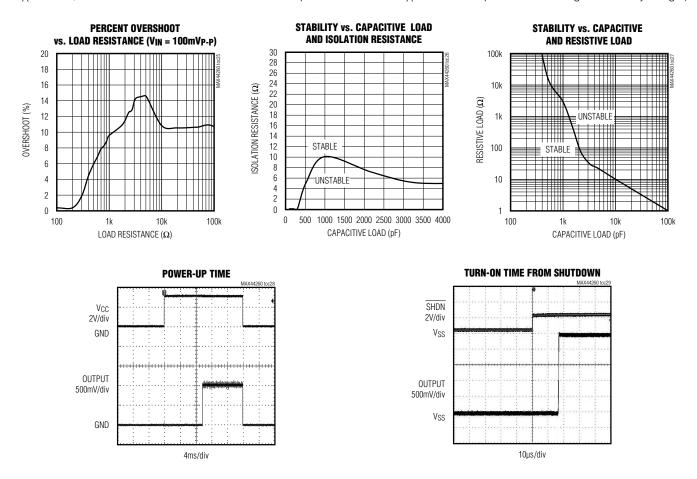
### **Typical Operating Characteristics (continued)**



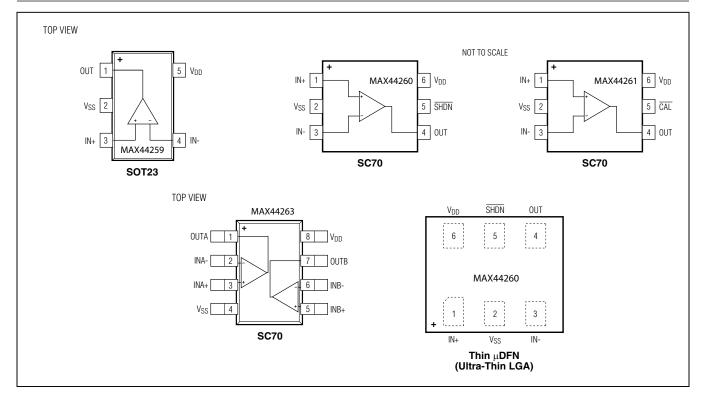
### **Typical Operating Characteristics (continued)**



### **Typical Operating Characteristics (continued)**



#### **Pin Configurations**



### **Pin Description**

	PIN				
MAX44259	MAX44260	MAX44261	MAX44263	NAME	FUNCTION
3	1	1		IN+	Positive Input
2	2	2	4	VSS	Negative Power Supply. Bypass with a $0.1\mu F$ capacitor to ground.
4	3	3	_	IN-	Negative Input
1	4	4		OUT	Output
		5		CAL	Active-Low Calibrate Input
	5	—	_	SHDN	Active-Low Shutdown
5	6	6	8	VDD	Positive Power Supply. Bypass with a $0.1\mu F$ capacitor to ground.
		_	1	OUTA	Channel A Output
		—	2	INA-	Channel A Negative Input
	_	—	3	INA+	Channel A Positive Input
		_	5	INB+	Channel B Positive Input
		_	6	INB-	Channel B Negative Input
		_	7	OUTB	Channel B Output

#### **Detailed Description**

The MAX44259/MAX44260/MAX44261/MAX44263 are high-speed low-power op amps ideal for signal processing applications due to the device's high precision and low-noise CMOS inputs. The devices self-calibrate on power-up to eliminate effects of temperature and powersupply variation.

The MAX44260 also features a low-power shutdown mode that greatly reduces quiescent current while the device is not operational and recovers in 30µs.

The MAX44261 features a user-selectable self-calibration input that shuts down the device and allows it to be recalibrated at any time. The calibration routine takes 10ms.

### Crossover Distortion

These op amps feature a low-noise integrated charge pump that creates an internal voltage rail 1V above  $V_{DD}$ , which is used to power the input differential pair of PMOS transistors as shown in Figure 1. Such a unique architecture eliminates crossover distortion common in traditional CMOS input architecture (Figure 2), especially when used in a noninverting configuration, such as for Sallen-Key filters.

The charge pump's operating frequency lies well above the unity-gain frequency of the amplifier. Thanks to its highfrequency operation and ultra-quiet circuitry, the charge pump generates little noise, does not require external components, and is entirely transparent to the user.

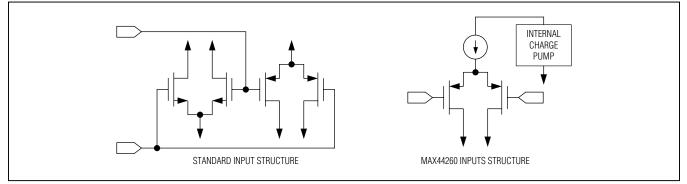


Figure 1. Comparing the Input Structure of the MAX44260 to Standard Op-Amp Inputs

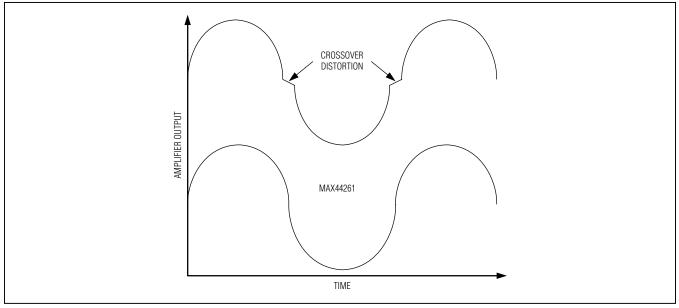


Figure 2. Crossover Distortion of Typical Amplifiers

#### **Applications Information**

#### **Power-Up Autotrim**

The ICs feature an automatic trim that self-calibrates the  $V_{OS}$  of these devices to less than 50µV of input offset voltage on power-up. This self-calibration feature allows the device to eliminate input offset voltage effects due to power supply and operating temperature variation simply by cycling its power. The autotrim sequence takes approximately 10ms to complete and is triggered by an internal power-on-reset (POR) circuitry. During this time, the inputs and outputs are put into high impedance and left unconnected. The MAX44261 can also be forced into a self-calibration cycle by pulling the CAL input low for 1µs. This input also puts the part into shutdown mode.

#### **Shutdown Operation**

The MAX44260 features an active-low shutdown mode that puts both inputs and outputs into high impedance and substantially lowers the quiescent current to less than  $1\mu$ A. Putting the output into high impedance allows multiple outputs to be multiplexed onto a single output line without the additional external buffers. The device does not self-calibrate when exiting shutdown mode

and retains its power-up trim settings. Figure 3 shows that the device also recovers from shutdown in under  $30\mu s$ .

The MAX44261 features a recalibrate input that acts the same as the shutdown mode of the MAX44260. However, when the input is pulled low, the device goes through a self-calibration sequence again (Figure 3).

The shutdown logic levels of the devices are independent of supply, allowing the shutdown feature of the device to operate off of a 1.8V or 3.3V microcontroller, regardless of supply voltage.

#### Rail-to-Rail Input/Output

The input voltage range of the ICs extends 100mV above  $V_{DD}$  and below  $V_{SS}$ . The wide input commonmode voltage range allows the op amp to be used as a buffer and as a differential amplifier in a wide-variety of signal processing applications. Output voltage high/ low is designed to be only 50mV above  $V_{SS}$  and below  $V_{DD}$  allowing maximum dynamic range in single-supply applications. The high output current and capacitance drive capability of the devices make them ideal as an ADC driver and a line driver.

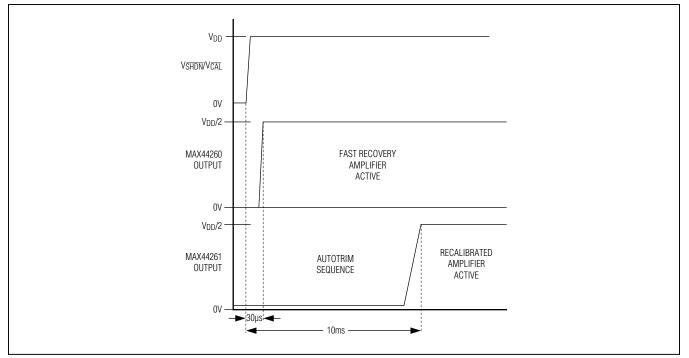


Figure 3. CAL vs. SHDN Input Operation

#### **Input Bias Current**

The ICs feature a high-impedance CMOS input stage and a specialized ESD structure that allows low-input bias current operation at low-input, common-mode voltages. Low-input bias current is useful when interfacing with high-ohmic sensors. It is also beneficial for designing transimpedance amplifiers for photodiode sensors. This makes these devices ideal for ground-referenced medical and industrial sensor applications.

#### **Active Filters**

The MAX44259/MAX44260/MAX44261/MAX44263 are ideal for a wide variety of active filter circuits that make use of their wide bandwidth, rail-to-rail input/output stages and high-impedance CMOS inputs. The *Typical Application Circuit* shows an example Sallen-Key active filter circuit with a corner frequency of 10kHz. At low frequencies, the amplifier behaves like a simple low-distortion noninverting buffer, while its high bandwidth gives excellent stopband attenuation above its corner frequency. See the *Typical Application Circuit*.

#### Driver for Interfacing with the MAX11645 ADC

**Ordering Information** 

The ICs' tiny size and low noise makes them a good fit for driving 12- to 16-bit resolution ADCs in space-constrained applications. The *Typical Application Circuit* shows the MAX44260 amplifier output connected to a lowpass filter driving the MAX11645 ADC. The MAX11645 is part of a family of 3V and 5V, 12-bit and 10-bit, 2-channel ADCs.

The MAX11645 offers sample rates up to 94ksps and measures two single-ended inputs or one differential input. These ADCs dissipate 670µA at the maximum sampling rate, but just 6µA at 1ksps and 0.5µA in shutdown. Offered in the ultra-tiny, 1.9mm x 2.2mm WLP and µMAX-8 packages, the MAX11645 ADCs are an ideal fit to pair with the MAX44260/MAX44261/MAX44263 amplifiers in portable applications.

Where higher resolution is required, refer to the MAX1069 (14-bit) and MAX1169 (16-bit) ADC families.

#### **Chip Information**

PROCESS: BiCMOS

### on\_\_\_\_\_

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
<b>Max44259</b> AUK+	-40°C to +125°C	5 SOT23	+AMFX
MAX44260AXT+	-40°C to +125°C	6 SC70	+AEB
MAX44260AYT+	-40°C to +125°C	6 Thin µDFN (Ultra-Thin LGA)	+AY
MAX44261AXT+	-40°C to +125°C	6 SC70	+AEC
MAX44263AXA+	-40°C to +125°C	8 SC70	+AAG

+Denotes a lead(Pb)-free/RoHS-compliant package.

#### **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
5 SOT23	U5N+4	<u>21-0057</u>	<u>90-0174</u>
6 SC70	X6SN+1	<u>21-0077</u>	<u>90-0189</u>
6 Thin μDFN (Ultra-Thin LGA)	Y61A1+1	<u>21-0190</u>	<u>90-0233</u>
8 SC70	X8CN+1	<u>21-0460</u>	<u>90-0348</u>

#### **Revision History**

14

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED	
0	6/11	Initial release	_	
1	8/11	Added thin µDFN (ultra-thin LGA) package and updated slew rate and TOC 29	1, 2, 3, 8, 9, 12	
2	10/11	Removed future product information from data sheet	12	
3	2/12	Revised Electrical Characteristics and the Power-Up Autotrim section	2, 3, 11	
4	7/12	Revised Electrical Characteristics and Typical Operating Characteristics	3, 6	
5	10/12	Added the MAX44263 and revised the <i>Electrical Characteristics, Pin Description,</i> and <i>Pin Configuration</i> .	1–17	
6	12/12	Revised Typical Operating Characteristics	7	
7	9/14	Added the MAX44259 to data sheet.	1–14	
8	12/14	Revised General Description and Benefits and Features section	1	
9	3/15	Revised Electrical Characteristics	2	



Maxim Integrated cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim Integrated product. No circuit patent licenses are implied. Maxim Integrated reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.

#### Maxim Integrated 160 Rio Robles, San Jose, CA 95134 USA 1-408-601-1000

© 2015 Maxim Integrated Products, Inc. The Maxim logo and Maxim Integrated are trademarks of Maxim Integrated Products, Inc.